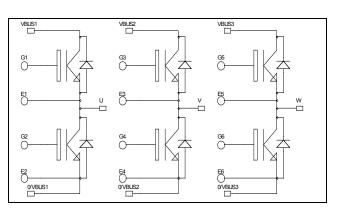


Triple phase leg NPT IGBT Power Module



VBUS2

⊕ G3 © E3

⊕ E4

 $V_{CES} = 600V$ $I_C = 90A$ @ $T_C = 80$ °C

Application

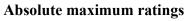
- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Non Punch Through (NPT) fast IGBT
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 100 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
 - Symmetrical design
 - Lead frames for power connections
- High level of integration



- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Very low (12mm) profile
- Easy paralleling due to positive TC of VCEsat
- Each leg can be easily paralleled to achieve a phase leg of three times the current capability
- Module can be configured as a three phase bridge
- Module can be configured as a boost followed by a full bridge
- RoHS compliant



VBUS1

0/VBUS1

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage		600	V
Ţ	Continuous Collector Current	$T_c = 25^{\circ}C$	110	
I_{C}	Continuous Conector Current	$T_c = 80$ °C	90	A
I_{CM}	Pulsed Collector Current	$T_c = 25^{\circ}C$	315	
V_{GE}	Gate – Emitter Voltage		±20	V
P_{D}	Maximum Power Dissipation	$T_c = 25^{\circ}C$	416	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 150^{\circ}C$	200A @ 600V	

VBUS3

😘 🗚 प्रमाजन: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

1 - 7



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
Ţ	Zero Gate Voltage Collector Current	$V_{GE} = 0V$	$T_i = 25^{\circ}C$			250	^
I_{CES}	Zero Gate Voltage Collector Current	$V_{CE} = 600V$	$T_{i} = 125^{\circ}C$			500	μΑ
**	C. II. day Farittan and anti-m Walkers	$V_{GE} = 15V$	$T_j = 25^{\circ}C$		2.0	2.5	V
$V_{CE(sat)}$	Collector Emitter saturation Voltage	$I_C = 90A$	$T_j = 125$ °C		2.2		V
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 1 \text{mA}$		3		5	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20 \text{ V}, V_{CE} = 0 \text{ V}$				±150	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$			4300		
C_{oes}	Output Capacitance	$V_{CE} = 25V$			470		pF
C_{res}	Reverse Transfer Capacitance	f=1MHz			400		
Q_{g}	Total gate Charge	$V_{GE} = 15V$			330		
Q_{ge}	Gate – Emitter Charge	$V_{\text{Bus}} = 300 \text{V}$			290		nC
Q_{gc}	Gate – Collector Charge	$I_C = 90A$			200		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switch	ning (25°C)		26		
$T_{\rm r}$	Rise Time	$V_{GE} = 15V$			25		
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 400V$ $I_{C} = 90A$		150		ns	
$T_{\rm f}$	Fall Time	$R_G = 5 \Omega$			30		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (125°C) $V_{GE} = 15V$ $V_{Bus} = 400V$ $I_{C} = 90A$			26		ns
$T_{\rm r}$	Rise Time				25		
$T_{d(off)}$	Turn-off Delay Time				170		
T_{f}	Fall Time	$R_G = 5 \Omega$	Ï		40		
Eon	Turn-on Switching Energy	$V_{GE} = 15V$ $V_{Bus} = 400V$	$T_j = 125$ °C		4.3		Т
E_{off}	Turn-off Switching Energy	$I_C = 90A$ $R_G = 5 \Omega$	$T_j = 125$ °C		3.5		mJ

Reverse diode ratings and characteristics

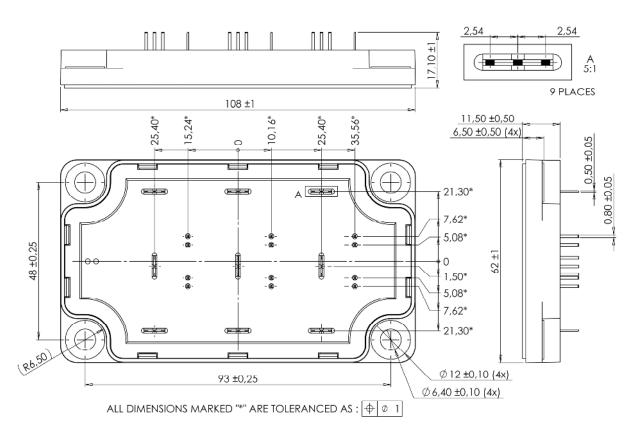
Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			600			V
т	Maximum Reverse Leakage Current	V _R =600V	$T_j = 25^{\circ}C$			250	^
I_{RM}			$T_j = 125$ °C			500	μA
I_{F}	DC Forward Current		$Tc = 70^{\circ}C$		60		Α
	Diode Forward Voltage	$I_F = 60A$			1.6	1.8	
$V_{\rm F}$		$I_F = 120A$			1.9		V
		$I_F = 60A$	$T_j = 125$ °C		1.4		
t _{rr}	Reverse Recovery Time	$I_F = 60A$ $V_R = 400V$	$T_j = 25^{\circ}C$		130		ns
			$T_j = 125$ °C		170		115
Qrr	Reverse Recovery Charge	$di/dt = 200A/\mu s \qquad T_j = 2$	$T_j = 25$ °C		220		пC
			$T_{i} = 125^{\circ}C$		920		IIC



Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
D	Junction to Case Thermal Resistance		IGBT			0.3	°C/W
R_{thJC}			Diode			0.9	C/ W
V_{ISOL}	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range			-40		150	
T_{STG}	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M6	3		5	N.m
Wt	Package Weight	·				250	g

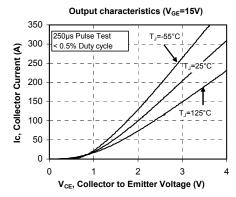
SP6-P Package outline (dimensions in mm)

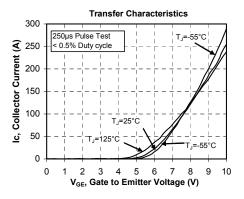


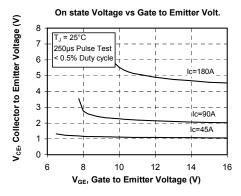
See application note 1902 - Mounting Instructions for SP6-P (12mm) Power Modules on www.microsemi.com

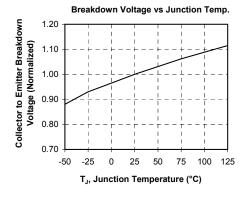


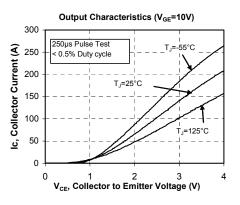
Typical Performance Curve

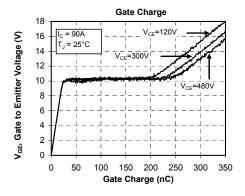


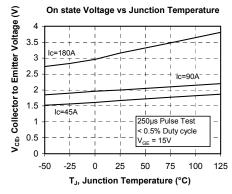


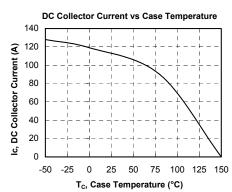




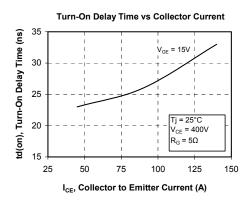


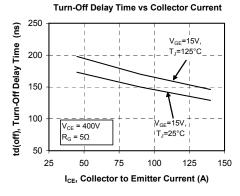


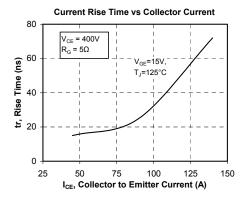


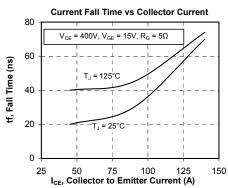


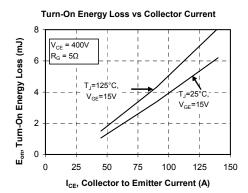


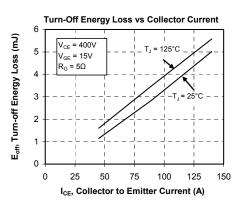


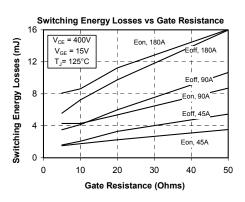


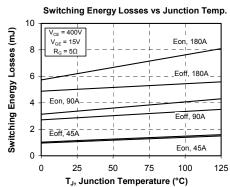




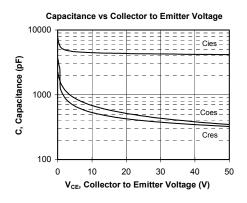


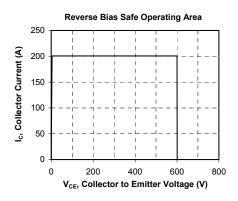




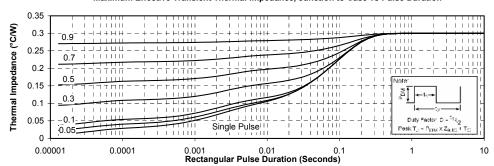


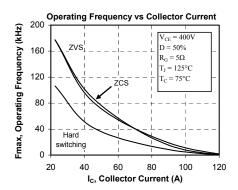






Maximum Effective Transient Thermal Impedance, Junction to Case vs Pulse Duration







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